

MPSA42, MPSA43

High Voltage Transistors

NPN Silicon



ON Semiconductor®

<http://onsemi.com>

Features

- These are Pb-Free Devices*

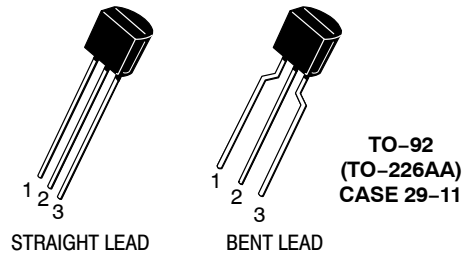
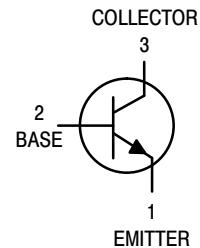
MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage MPSA43 MPSA42	V_{CEO}	200 300	Vdc
Collector–Base Voltage MPSA43 MPSA42	V_{CBO}	200 300	Vdc
Emitter–Base Voltage	V_{EBO}	6.0	Vdc
Collector Current – Continuous	I_C	500	mAdc
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	625 5.0	mW mW/ $^\circ\text{C}$
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	1.5 12	W mW/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$

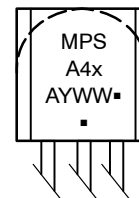
THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	200	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	83.3	$^\circ\text{C}/\text{W}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



MARKING DIAGRAM



- x = 2 or 3
 - A = Assembly Location
 - Y = Year
 - WW = Work Week
 - = Pb-Free Package
- (Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 3 of this data sheet.

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Collector–Emitter Breakdown Voltage (Note 1) (I _C = 1.0 mA _{dc} , I _B = 0)	MPSA42 MPSA43	V _{(BR)CEO}	300 200	– –	V _{dc}
Collector–Base Breakdown Voltage (I _C = 100 μA _{dc} , I _E = 0)	MPSA42 MPSA43	V _{(BR)CBO}	300 200	– –	V _{dc}
Emitter–Base Breakdown Voltage (I _E = 100 μA _{dc} , I _C = 0)		V _{(BR)EBO}	6.0	–	V _{dc}
Collector Cutoff Current (V _{CB} = 200 V _{dc} , I _E = 0) (V _{CB} = 160 V _{dc} , I _E = 0)	MPSA42 MPSA43	I _{CBO}	– –	0.1 0.1	μA _{dc}
Emitter Cutoff Current (V _{EB} = 6.0 V _{dc} , I _C = 0) (V _{EB} = 4.0 V _{dc} , I _C = 0)	MPSA42 MPSA43	I _{EBO}	– –	0.1 0.1	μA _{dc}
ON CHARACTERISTICS (Note 1)					
DC Current Gain (I _C = 1.0 mA _{dc} , V _{CE} = 10 V _{dc}) (I _C = 10 mA _{dc} , V _{CE} = 10 V _{dc}) (I _C = 30 mA _{dc} , V _{CE} = 10 V _{dc})		h _{FE}	25 40 40	– – –	–
Collector–Emitter Saturation Voltage (I _C = 20 mA _{dc} , I _B = 2.0 mA _{dc})	MPSA42 MPSA43	V _{CE(sat)}	– –	0.5 0.4	V _{dc}
Base–Emitter Saturation Voltage (I _C = 20 mA _{dc} , I _B = 2.0 mA _{dc})		V _{BE(sat)}	–	0.9	V _{dc}
SMALL-SIGNAL CHARACTERISTICS					
Current–Gain – Bandwidth Product (I _C = 10 mA _{dc} , V _{CE} = 20 V _{dc} , f = 100 MHz)		f _T	50	–	MHz
Collector–Base Capacitance (V _{CB} = 20 V _{dc} , I _E = 0, f = 1.0 MHz)	MPSA42 MPSA43	C _{cb}	– –	3.0 4.0	pF

1. Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.

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ORDERING INFORMATION

Device	Package	Shipping†
MPSA42G	TO-92 (Pb-Free)	5000 Units / Box
MPSA42RL1G	TO-92 (Pb-Free)	2000 / Tape & Reel
MPSA42RLRAG	TO-92 (Pb-Free)	2000 / Tape & Reel
MPSA42RLRMG	TO-92 (Pb-Free)	2000 / Ammo Pack
MPSA42RLRPG	TO-92 (Pb-Free)	2000 / Ammo Pack
MPSA42ZL1G	TO-92 (Pb-Free)	2000 / Ammo Pack

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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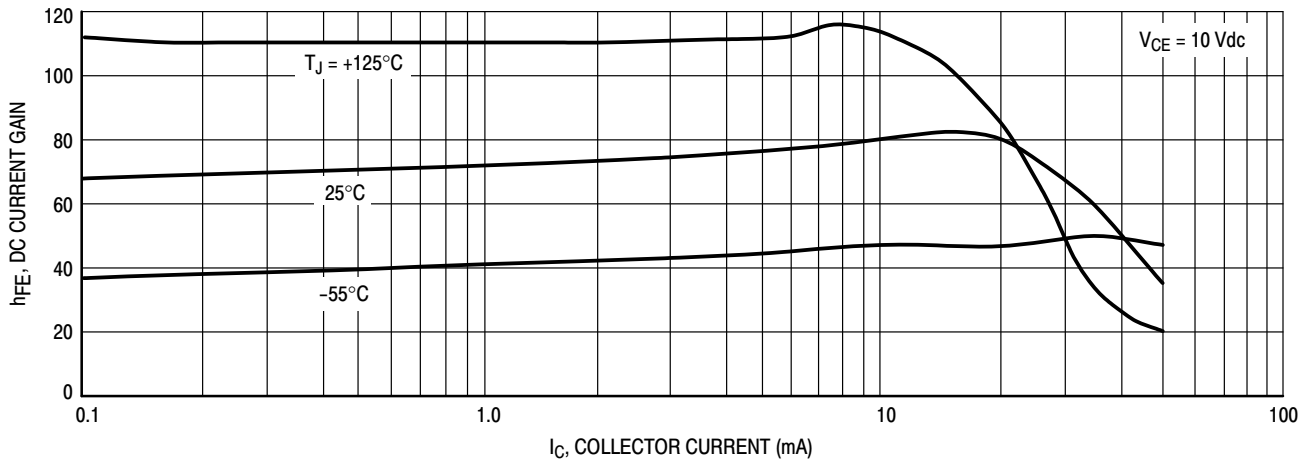


Figure 1. DC Current Gain

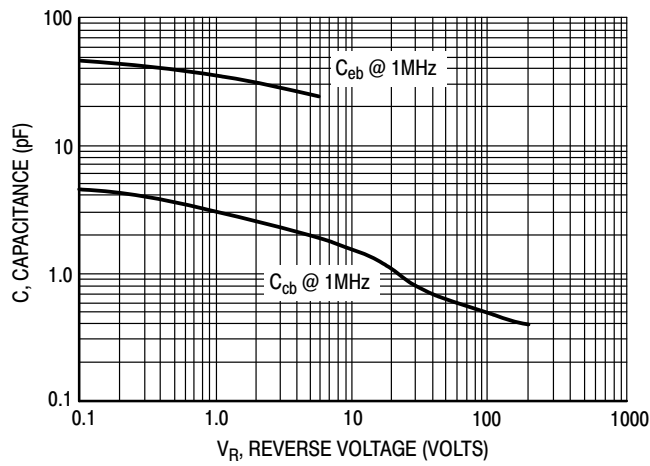


Figure 2. Capacitance

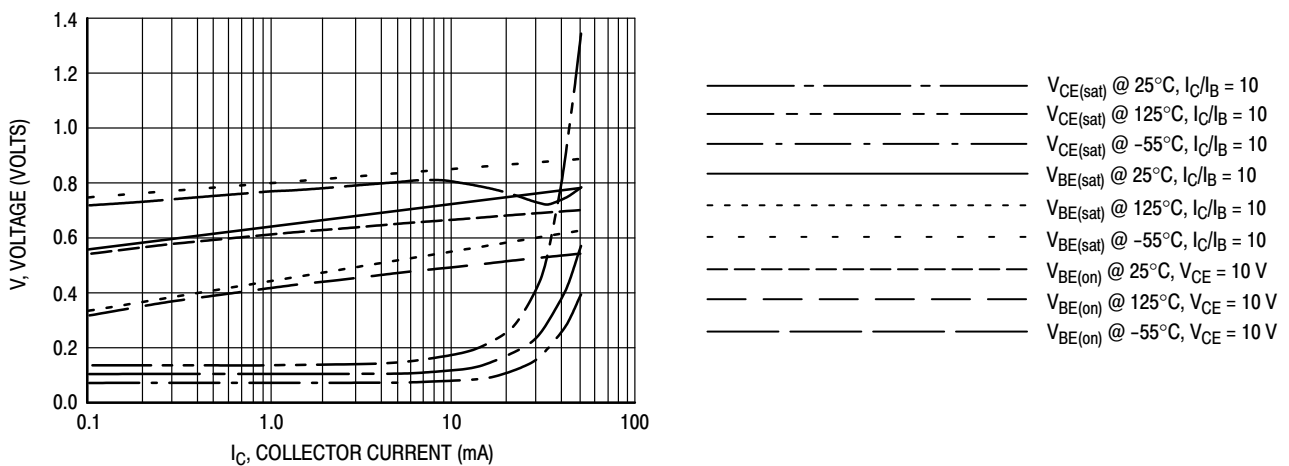


Figure 3. "ON" Voltages

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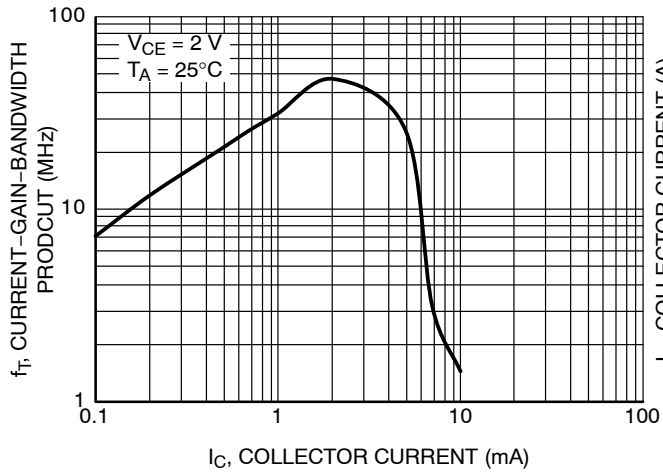


Figure 4. Current-Gain-Bandwidth Product

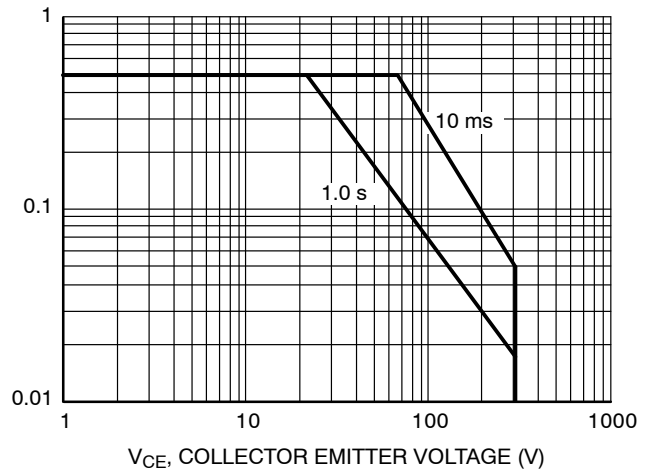
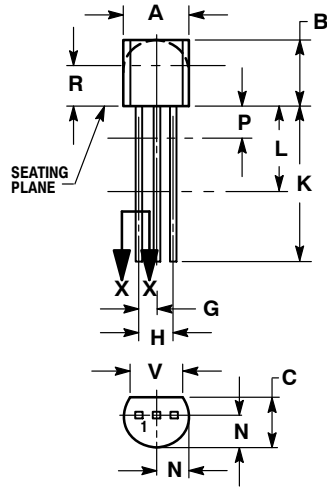


Figure 5. Safe Operating Area

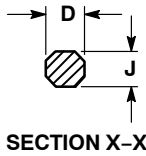
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PACKAGE DIMENSIONS

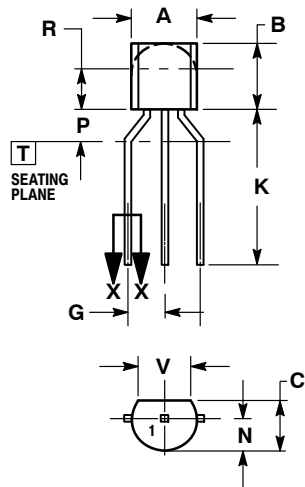
TO-92 (TO-226)
CASE 29-11
ISSUE AN



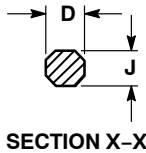
STRAIGHT LEAD



SECTION X-X



BENT LEAD



SECTION X-X

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500	---	12.70	---
L	0.250	---	6.35	---
N	0.080	0.105	2.04	2.66
P	---	0.100	---	2.54
R	0.115	---	2.93	---
V	0.135	---	3.43	---

STYLE 1:

1. PIN 1. EMITTER
2. BASE
3. COLLECTOR

NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	MILLIMETERS	
	MIN	MAX
A	4.45	5.20
B	4.32	5.33
C	3.18	4.19
D	0.40	0.54
G	2.40	2.80
J	0.39	0.50
K	12.70	---
N	2.04	2.66
P	1.50	4.00
R	2.93	---
V	3.43	---

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